

UP04316

Silicon NPN epitaxial planar transistor (Tr1)
Silicon PNP epitaxial planar transistor (Tr2)

For switching
For digital circuit

■ Features

- Two elements incorporated into one package
(Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number of Element

- UNR1216 (UN1216) + UNR1116 (UN1116)

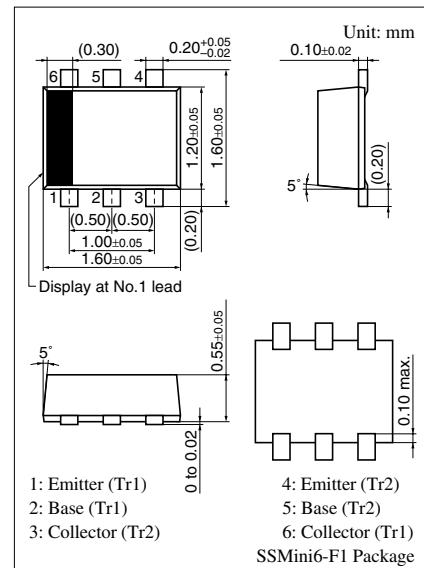
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

	Parameter	Symbol	Rating	Unit
Tr1	Collector to base voltage	V_{CBO}	50	V
	Collector to emitter voltage	V_{CEO}	50	V
	Collector current	I_C	100	mA
Tr2	Collector to base voltage	V_{CBO}	-50	V
	Collector to emitter voltage	V_{CEO}	-50	V
	Collector current	I_C	-100	mA
Overall	Total power dissipation	P_T	125	mW
	Junction temperature	T_j	125	°C
	Storage temperature	T_{stg}	-55 to +125	°C

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

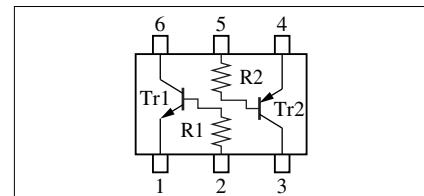
- Tr1

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector to base voltage	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	50			V
Collector to emitter voltage	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Collector cutoff current	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μA
	I_{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			0.01	mA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	160		460	
Collector to emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$			0.25	V
High-level output voltage	V_{OH}	$V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	4.9			V
Low-level output voltage	V_{OL}	$V_{CC} = 5 \text{ V}, V_B = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			0.2	V
Input resistance	R_I		-30%	4.7	+30%	$\text{k}\Omega$
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz



Marking Symbol: 7U

Internal Connection



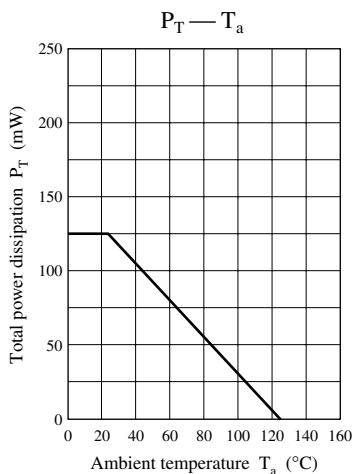
Note) The part number in the parenthesis shows conventional part number.

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

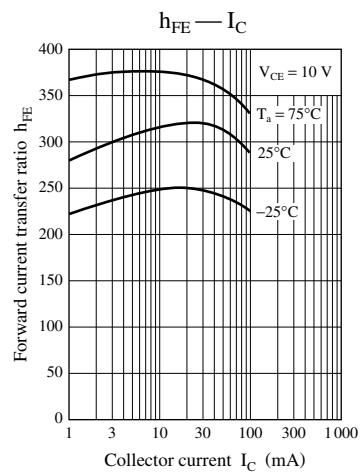
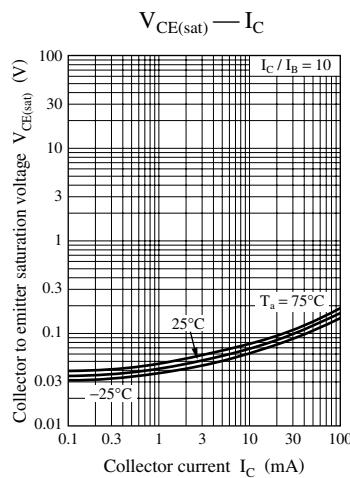
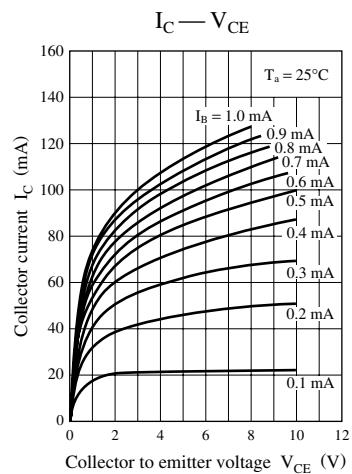
- Tr2

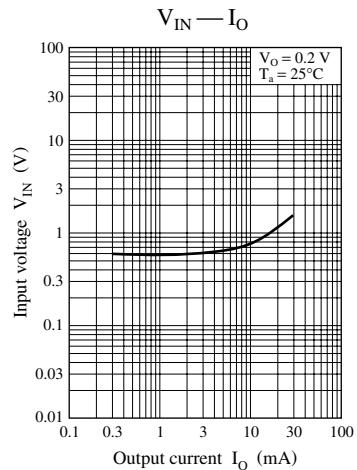
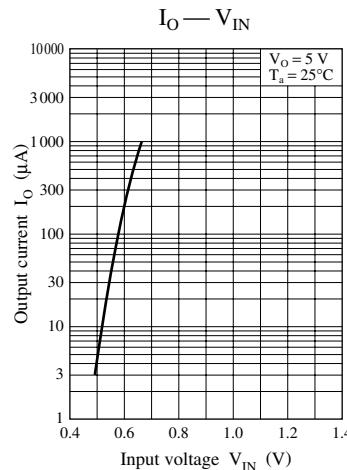
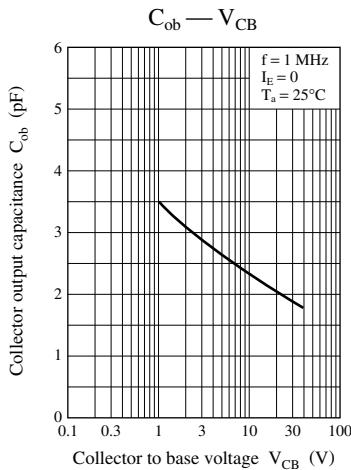
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector to base voltage	V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V
Collector to emitter voltage	V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
Collector cutoff current	I_{CBO}	$V_{\text{CB}} = -50 \text{ V}, I_E = 0$			-0.1	μA
	I_{CEO}	$V_{\text{CE}} = -50 \text{ V}, I_B = 0$			-0.5	
Emitter cutoff current	I_{EBO}	$V_{\text{EB}} = -6 \text{ V}, I_C = 0$			-0.5	mA
Forward current transfer ratio	h_{FE}	$V_{\text{CE}} = -10 \text{ V}, I_C = -5 \text{ mA}$	160	460		
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			-0.25	V
High-level output voltage	V_{OH}	$V_{\text{CC}} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Low-level output voltage	V_{OL}	$V_{\text{CC}} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			-0.2	V
Input resistance	R_I		-30%	4.7	+30%	$\text{k}\Omega$
Transition frequency	f_T	$V_{\text{CB}} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

Common characteristics chart

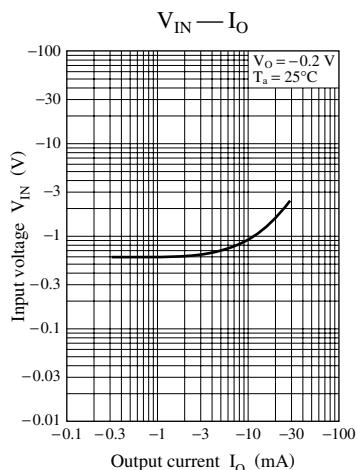
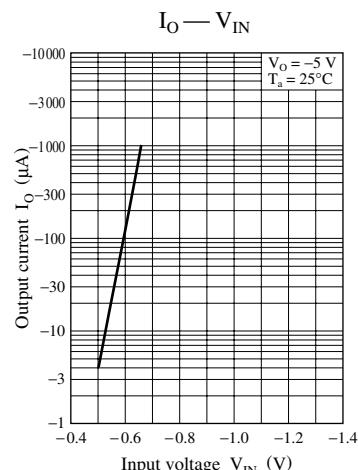
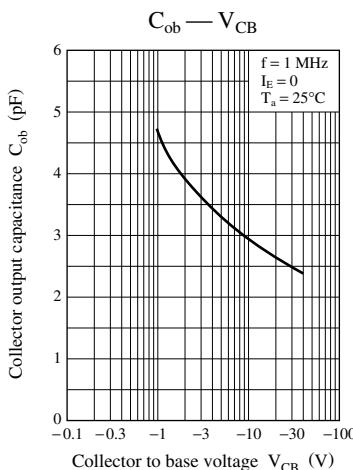
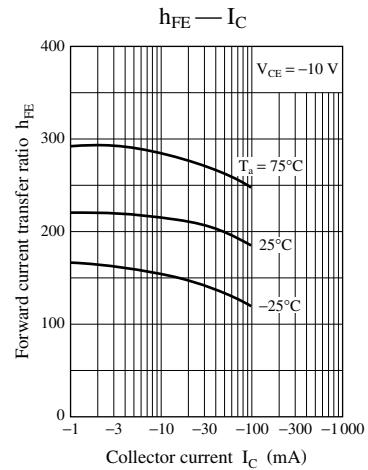
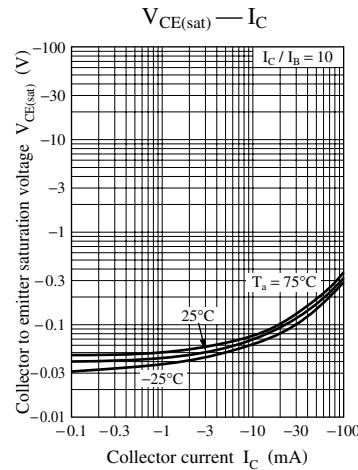
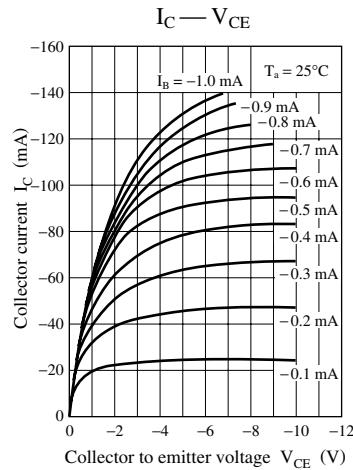


Characteristics chart of Tr1





Characteristics chart of Tr2



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